# NSN 5962-01-376-2199

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# **Body Length:**

1.290 inches

## **Body Width:**

Between 0.500 inches and 0.610 inches

## **Body Height:**

0.210 inches

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

### **End Application:**

5975-01-253-6144 junction box

### **Features Provided:**

Programmed and bipolar and schottky and monolithic and w/enable and w/inhibit and high impedance and w/buffered output

#### Inclosure Material:

Ceramic

### Inclosure Configuration:

Dual-in-line

### **Output Logic Form:**

Transistor-transistor logic

### Input Circuit Pattern:

14 input

### Case Outline Source And Designator:

D-3 mil-m-38510

### **Current Rating Per Characteristic:**

190.00 milliamperes reverse current, dc absolute

### **Terminal Surface Treatment:**

Solder

### Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

### **Capitance Rating Per Characteristic:**

10.00 input pascal industrial light tank stock and 15.00 output pascal industrial light tank stock

#### **Time Rating Per Chacteristic:**

70.00 nanoseconds access

#### Memory Device Type:

Prom

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# **Terminal Type And Quantity:**

24 printed circuit

#### Shelf Life:

N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

